wherein the first light-emitting layer is separated from the second light-emitting layer by the structure body, and

wherein at least a part of the structure body is in contact with the bonding layer.

22. The light-emitting device according to claim **21**,

wherein the third electrode layer is separated from the fourth electrode layer by the structure body.

23. The light-emitting device according to claim **21**,

wherein the first substrate and the second substrate have flexibility.

24. The light-emitting device according to claim **21**,

wherein each of the first electrode layer and the second electrode layer is electrically connected to a transistor.

25. The light-emitting device according to claim **21**,

wherein the second substrate has a colored layer which is capable of transmitting light of a specific wavelength band.

26. The light-emitting device according to claim **21**,

wherein each of the first light-emitting layer and the second light-emitting layer includes a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer.

27. The light-emitting device according to claim **21**,

wherein each of the first light-emitting layer and the second light-emitting layer is capable of emitting white light.

28. The light-emitting device according to claim **21**,

wherein a side portion of the structure body protrudes from a bottom of the structure body in a direction parallel to the first substrate.

29. The light-emitting device according to claim **21**,

wherein the third electrode layer and the fourth electrode layer are electrically connected to a common electrode layer.

30. An electronic device using the light-emitting device described in claim **21**.

31. A light emitting device comprising:

a first electrode layer and a second electrode layer over a first substrate;

a partition wall over the first electrode layer and the second electrode layer;

a structure body over the partition wall;

a first light-emitting layer over the first electrode layer, the partition wall and the structure body;

a second light-emitting layer over the second electrode layer, the partition wall and the structure body;

a third electrode layer over the first light-emitting layer;

a fourth electrode layer over, the second light-emitting layer;

a bonding layer over the third electrode layer and the fourth electrode layer; and

a second substrate over the bonding layer,

wherein the first light-emitting layer is separated from the second light-emitting layer by the structure body, and

wherein at least a part of the structure body is in contact with the third electrode layer and the fourth electrode layer.

32. The light-emitting device according to claim **31**,

wherein the third electrode layer and the fourth electrode layer are continuous at the structure body.

33. The light-emitting device according to claim **31**,

wherein the first substrate and the second substrate have flexibility.

34. The light-emitting device according to claim **31**,

wherein each of the first electrode layer and the second electrode layer is electrically connected to a transistor.

35. The light-emitting device according to claim **31**,

wherein the second substrate has a colored layer which is capable of transmitting light of a specific wavelength band.

36. The light-emitting device according to claim **31**,

wherein each of the first light-emitting layer and the second light-emitting layer includes a hole injection layer, a hole transport layer, an electron transport layer, and an electron injection layer.

37. The light-emitting device according to claim **31**,

wherein each of the first light-emitting layer and the second light-emitting layer is capable of emitting white light.

38. The light-emitting device according to claim **31**,

wherein a side portion of the structure body protrudes from a bottom of the structure body in a direction parallel to the first substrate.

39. The light-emitting device according to claim **31**,

wherein the third electrode layer and the fourth electrode layer are electrically connected to a common electrode layer.

40. An electronic device using the light-emitting device described in claim **31**.

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